

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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PHOTOCOUPLER PS8601L

HIGH SPEED ANALOG OUTPUT TYPE 8-PIN PHOTOCOUPLER

-NEPOC Series-

DESCRIPTION

The PS8601 and PS8601L are 8-pin high speed photocouplers containing a GaAlAs LED on input side and a PN photodiode and a high speed amplifier transistor on output side on one chip. The PS8601 is in a plastic DIP (Dual Inline Package). The PS8601L is lead bending type (Gull wing) for surface mount.

FEATURES

High supply voltage (Vcc = 35 V MAX.)
 High speed response (tphl, tplh = 0.8 μs MAX.)
 High isolation voltage (BV = 5 000 Vr.m.s.)

· TTL, CMOS compatible with a resistor

· For Infrared reflow soldering

· Ordering number of tape product: PS8601L-E3, E4: 1 000 pcs/reel

Safety standards

• UL approved: File No. E72422 (S)

· BSI approved: No. 8004

· VDE0884 approved (Option) No.91877

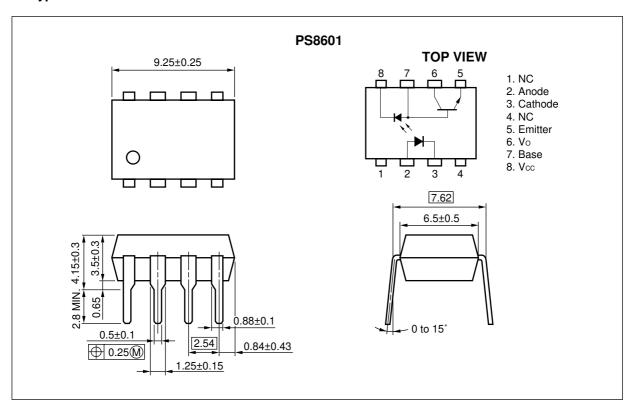
APPLICATIONS

- · Interface for measurement or control equipment
- Substitutions for relays and pulse transformers

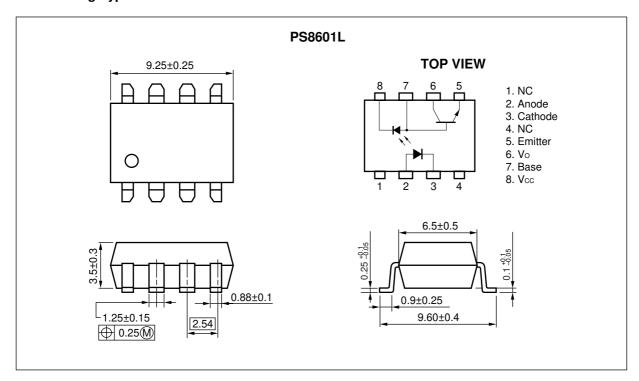
The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

★ PACKAGE DIMENSIONS (UNIT: mm)

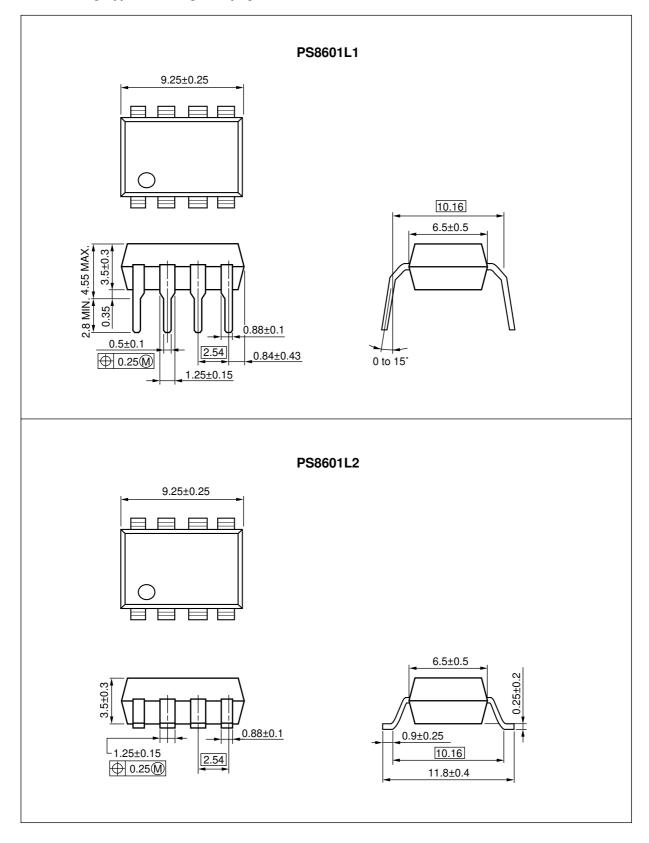
DIP Type



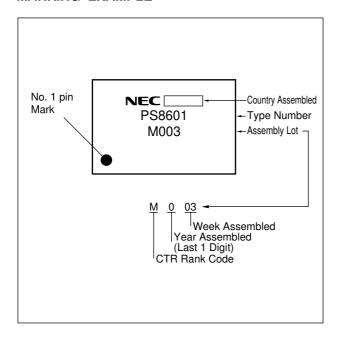
Lead Bending Type



★ Lead Bending Type For Long Creepage Distance



MARKING EXAMPLE



ORDERING INFORMATION (Solder Contains Lead)

Part Number	Package	Packing Style	Application Part Number*1
PS8601	8-pin DIP	Magazine case 50 pcs	PS8601
PS8601L			PS8601L
PS8601L1			
PS8601L2			
PS8601L-E3		Embossed Tape 1 000 pcs/reel	
PS8601L-E4			
PS8601-V		Magazine case 50 pcs	PS8601
PS8601L-V			PS8601L
PS8601L1-V			
PS8601L2-V			
PS8601L-V-E3		Embossed Tape 1 000 pcs/reel	
PS8601L-V-E4			

^{*1} For the application of the Safety Standard, following part number should be used.

ORDERING INFORMATION (Pb-Free)

Part Number	Package	Packing Style	Application Part Number*1
PS8601-A	8-pin DIP	Magazine case 50 pcs	PS8601
PS8601L-A			PS8601L
PS8601L1-A			
PS8601L2-A			
PS8601L-E3-A		Embossed Tape 1 000 pcs/reel	
PS8601L-E4-A			
PS8601-V-A		Magazine case 50 pcs	PS8601
PS8601L-V-A			PS8601L
PS8601L1-V-A			
PS8601L2-V-A			
PS8601L-V-E3-A		Embossed Tape 1 000 pcs/reel	
PS8601L-V-E4-A			

^{*1} For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (TA = 25 °C, unless otherwise specified)

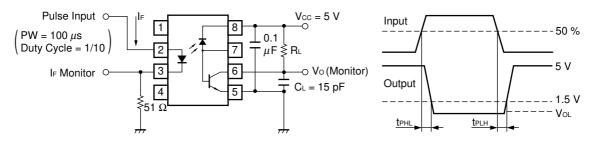
Parameter		Symbol	Ratings	Unit
Diode	Forward Current	I F	25	mA
	Reverse Voltage	VR	5	٧
	Power Dissipation	Po	45	mW
Detector	Supply Voltage	Vcc	35	V
	Output Voltage	Vo	35	٧
	Output Current	lo	8	mA
	Power Dissipation	Pc	100	mW
Isolation Voltage*1		BV	5 000	Vr.m.s.
Operating Ambient Temperature		TA	−55 to +100	°C
Storage Temperature		T _{stg}	-55 to +100	°C

^{*1} AC voltage for 1 minute at $T_A = 25$ °C, RH = 60 % between input and output.

ELECTRICAL CHARACTERISTICS (TA = 25 °C)

	Parameter	Symbol	Conditions	MIN.	TYP.*1	MAX.	Unit
Diode	Forward Voltage	VF	IF = 16 mA		1.7	2.2	٧
	Reverse Current	IR	V _R = 5 V			10	μΑ
	Forward Voltage Temperature Coefficent	ΔVF/ΔT	IF = 16 mA		-1.6		mV/°C
	Terminal Capacitance	Ct	V = 0 V, f = 1 MHz		60		pF
Detector	High Level Output Current	Іон(1)	IF = 0 mA, Vcc = Vo = 5.5 V		3	500	nA
	High Level Output Current	Іон(2)	IF = 0 mA, Vcc = Vo = 35 V			100	μА
	Low Level Output Voltage	Vol	IF = 16 mA, Vcc = 4.5 V, Io = 1.2 mA		0.1	0.4	V
	Low Level Supply Current	Iccl	IF = 16 mA, Vo = Open, Vcc = 35 V		50		μΑ
	High Level Supply Current	Іссн	IF = 0 mA, Vo = Open, Vcc = 35 V		0.01	1	μΑ
	DC Current Gain	hfE	Vo = 5 V, lo = 3 mA		100		
Coupled	Current Transfer Ratio	CTR	IF = 16 mA, Vcc = 4.5 V, Vo = 0.4 V	15			%
	Isolation Resistance	R _{I-O}	Vi-o = 1 kVDC	10 ¹¹			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1 MHz		0.7		pF
	Propagation Delay Time $(H \rightarrow L)^{*2}$	t PHL	$I_F = 16$ mA, $V_{CC} = 5$ V, $R_L = 1.9$ k Ω		0.5	0.8	μS
	Propagation Delay Time $(L \rightarrow H)^{*2}$	tрLн	$I_F = 16$ mA, $V_{CC} = 5$ V, $R_L = 1.9$ k Ω		0.3	0.8	μS

- *1 Typical values at T_A = 25 °C
- *2 Test circuit for propagation delay time



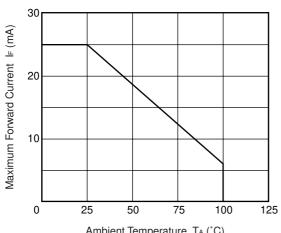
C∟ includes probe and stray wiring capacitance

USAGE CAUTIONS

- 1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
- 2. By-pass capacitor of more than 0.1 μ F is used between Vcc and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10 mm.
- ★ 3. Avoid storage at a high temperature and high humidity.

TYPICAL CHARACTERISTICS (TA = 25 °C, unless otherwise specified)

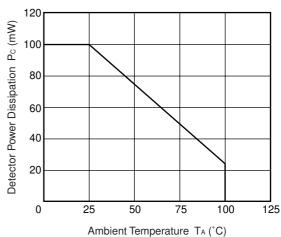




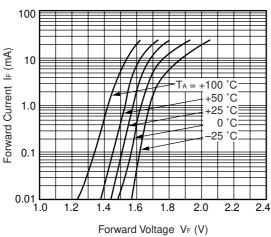
Ambient Temperature TA (°C)

vs. AMBIENT TEMPERATURE 120

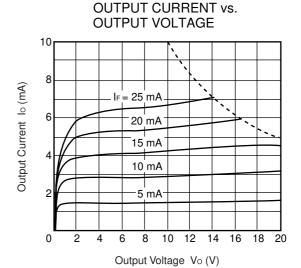
DETECTOR POWER DISSIPATION



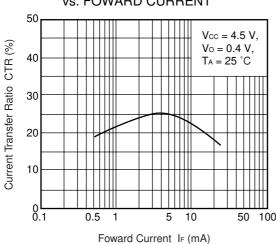
FORWARD CURRENT vs.



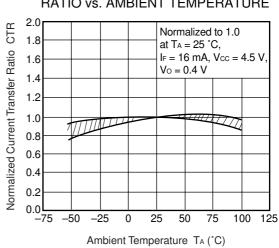
FORWARD VOLTAGE



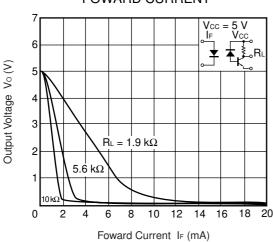
CURRENT TRANSFER RATIO vs. FOWARD CURRENT



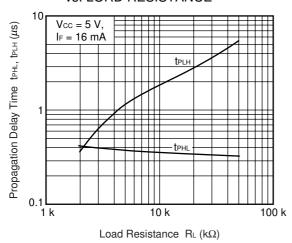
NORMALIZED CURRENT TRANSFER RATIO vs. AMBIENT TEMPERATURE



OUTPUT VOLTAGE vs. FOWARD CURRENT

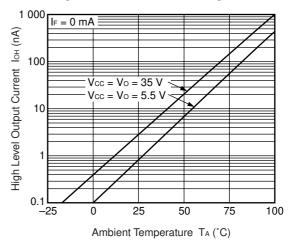


PROPAGATION DELAY TIME, vs. LORD RESISTANCE

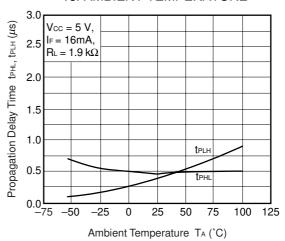


Remark The graphs indicate nominal characteristics.

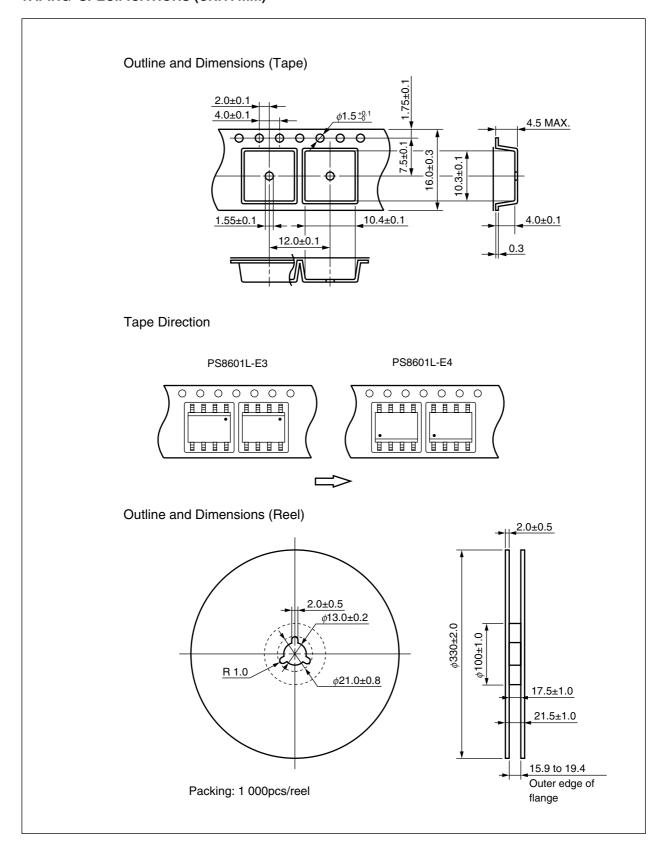
HIGH LEVEL OUTPUT CURRENT vs. AMBIENT TEMPERATURE



PROPAGATION DELAY TIME, vs. AMBIENT TEMPERATURE



* TAPING SPECIFICATIONS (UNIT: mm)



NOTES ON HANDLING

1. Recommended soldering conditions

(1) Infrared reflow soldering

· Peak reflow temperature 260°C or below (package surface temperature)

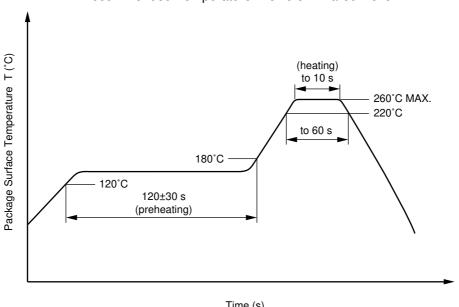
· Time of peak reflow temperature 10 seconds or less • Time of temperature higher than 220°C 60 seconds or less

• Time to preheat temperature from 120 to 180°C 120±30 s · Number of reflows Three

• Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt% is recommended.)

Recommended Temperature Profile of Infrared Reflow



Time (s)

(2) Wave soldering

 Temperature 260°C or below (molten solder temperature)

• Time 10 seconds or less

· Preheating conditions 120°C or below (package surface temperature)

· Number of times One (Allowed to be dipped in solder including plastic mold portion.)

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine

content of 0.2 Wt% is recommended.)

(3) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

2. Cautions regarding noise

Be aware that when voltage is applied suddenly between the photocoupler's input and output or between collector-emitters at startup, the output side may enter the on state, even if the voltage is within the absolute maximum ratings.

SPECIFICATION OF VDE MARKS LICENSE DOCUMENT (VDE0884)

Parameter	Symbol	Speck	Unit
$\label{eq:application} \mbox{Application classification (DIN VDE 0109)} \\ \mbox{for rated line voltages} \leq 300 \ \mbox{V}_{r.m.s.} \\ \mbox{for rated line voltages} \leq 600 \ \mbox{V}_{r.m.s.} \\ $		IV III	
Climatic test class (DIN IEC 68 Teil 1/09.80)		55/100/21	
Dielectric strength maximum operating isolation voltage Test voltage (partial discharge test, procedure a for type test and random test) $U_{pr} = 1.2 \times U_{\text{IORM}}, P_{d} < 5 \text{pC}$	UIORM Upr	890 1 068	V _{peak} V _{peak}
Test voltage (partial discharge test, procedure b for all devices test) $U_{pr}=1.6\times U_{IORM},P_d<5\;pC$	Upr	1 424	V_{peak}
Highest permissible overvoltage	Utr	8 000	V _{peak}
Degree of pollution (DIN VDE 0109)		2	
Clearance distance		> 7.0	mm
Creepage distance		> 7.0	mm
Comparative tracking index (DIN IEC 112/VDE 0303 part 1)	CTI	175	
Material group (DIN VDE 0109)		III a	
Storage temperature range	Tstg	-55 to +150	°C
Operating temperature range	TA	-55 to +100	°C
Isolation resistance, minimum value VIO = 500 V dc at TA = 25 °C VIO = 500 V dc at TA MAX. at least 100 °C	Ris MIN. Ris MIN.	10 ¹² 10 ¹¹	Ω Ω
Safety maximum ratings (maximum permissible in case of fault, see thermal derating curve) Package temperature Current (input current I _F , Psi = 0) Power (output or total power dissipation) Isolation resistance	Tsi Isi Psi	175 400 700	°C mA mW
$V_{10} = 500 \text{ V dc at T}_{A} = 175 ^{\circ}\text{C (Tsi)}$	Ris MIN.	10 ⁹	Ω

*



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Subject: Compliance with EU Directives

CEL certifies, to its knowledge, that semiconductor and laser products detailed below are compliant with the requirements of European Union (EU) Directive 2002/95/EC Restriction on Use of Hazardous Substances in electrical and electronic equipment (RoHS) and the requirements of EU Directive 2003/11/EC Restriction on Penta and Octa BDE.

CEL Pb-free products have the same base part number with a suffix added. The suffix –A indicates that the device is Pb-free. The –AZ suffix is used to designate devices containing Pb which are exempted from the requirement of RoHS directive (*). In all cases the devices have Pb-free terminals. All devices with these suffixes meet the requirements of the RoHS directive.

This status is based on CEL's understanding of the EU Directives and knowledge of the materials that go into its products as of the date of disclosure of this information.

Restricted Substance per RoHS	Concentration Limit per RoHS (values are not yet fixed)	Concentration contained in CEL devices		
Lead (Pb)	< 1000 PPM	-A Not Detected	-AZ (*)	
Mercury	< 1000 PPM	Not Detected		
Cadmium	< 100 PPM	Not Detected		
Hexavalent Chromium	< 1000 PPM	Not Detected		
PBB	< 1000 PPM	Not Detected		
PBDE	< 1000 PPM	Not Detected		

If you should have any additional questions regarding our devices and compliance to environmental standards, please do not hesitate to contact your local representative.

Important Information and Disclaimer: Information provided by CEL on its website or in other communications concerting the substance content of its products represents knowledge and belief as of the date that it is provided. CEL bases its knowledge and belief on information provided by third parties and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. CEL has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. CEL and CEL suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall CEL's liability arising out of such information exceed the total purchase price of the CEL part(s) at issue sold by CEL to customer on an annual basis.

See CEL Terms and Conditions for additional clarification of warranties and liability.